

## ICS840001-34

FEMTOCLOCKS<sup>TM</sup>CRYSTAL-TO-LVCMOS/LVTTL FREQUENCY SYNTHESIZER

#### GENERAL DESCRIPTION



The ICS840001-34 is a two output LVCMOS/LVTTL Synthesizer and a member of the HiPerClocks<sup>™</sup> family of high performance devices from ICS. One output is the LVCMOS/LVTTL main synthesized clock output (Q) and

one output is a three-state LVCMOS/LVTTL reference clock (REF\_CLK) output at the frequency of the crystal oscillator. The device can accept crystal from 15.3125MHz to 42.67MHz and can synthesize outputs from 81.67MHz to 213.33MHz.The ICS840001-34 has excellent <1ps phase jitter performance over the 637kHz - 10MHz integration range. The ICS840001-34 is packaged in a 3mm x 3mm 16-pin VFQFN, making it ideal for use on space constrained boards.

#### **F**EATURES

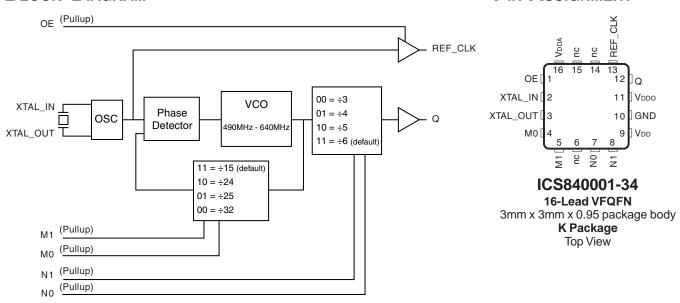
- (2) LVCMOS/LVTTL outputs, 20Ω typical output impedence
   (1) Main clock output (Q)
  - (1) Three-state reference clock output (REF\_CLK)
- Crystal oscillator interface can accept crystals from 15.3125MHz to 42.67MHz, 18pF parallel resonant crystal
- Output frequency range: 81.67MHz to 213.33MHz
- VCO range: 490MHz to 640MHz
- RMS phase jitter @ 106.25MHz, using a 26.5625MHz crystal (637kHz - 10MHz): 0.38ps (typical)
- 3.3V operating supply
- 0°C to 70°C ambient operating temperature

#### COMMON APPLICATION CONFIGURATION TABLE

	In	puts		Output Frequency	Application
Crystal	M Divider	VCO (MHz)	N Divider	(MHz)	Application
40	15	600	6	100	Serial Attached (SCSI), PCI Express™, Processor Clock
26.5625	24	637.5	6	106.25	Fibre Channel
40	15	600	4	150	Serial ATA (SATA), Processor Clock
26.5625	24	637.5	3	212.5	Fibre Channel 2
25	25	625	5	125	Ethernet
25	25	625	4	156.25	10 Gigabit Ethernet
22.5	25	562.5	3	187.5	12 Gigabit Ethernet
19.44	32	622.08	4	155.52	SONET

#### **BLOCK DIAGRAM**

### PIN ASSIGNMENT



The Preliminary Information presented herein represents a product in prototyping or pre-production. The noted characteristics are based on initial product characterization. Integrated Circuit Systems, Incorporated (ICS) reserves the right to change any circuitry or specifications without notice.



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TABLE 1. PIN DESCRIPTIONS

Number	Name	Ту	pe	Description
1	OE	Input	Pullup	Output enable pin. When HIGH, REF_CLK output is enabled. When LOW, forces REF_CLK to HiZ state. LVCMOS/LVTTL interface levels.
2,3	XTAL_OUT, XTAL_IN	Input		Crystal oscillator interface. XTAL_IN is the input. XTAL_OUT is the output.
4, 5	M0, M1	Input	Pullup	M divider inputs. LVCMOS/LVTTL interface levels. See Table 3B.
6, 14, 15	nc	Unused		No connect.
7, 8	N0, N1	Input	Pullup	Determines output divider value as defined in Table 3C. LVCMOS/LVTTL interface levels.
9	$V_{_{\mathrm{DD}}}$	Power		Core supply pin.
10	GND	Power		Power supply ground.
11	$V_{_{\mathrm{DDO}}}$	Power		Output supply pin.
12	Q	Output		Single-ended clock output. LVCMOS/LVTTL interface levels. 20Ω typical output impedance.
13	REF_CLK	Output		Single-ended three-state reference clock output. LVCMOS/LVTTL interface levels. $20\Omega$ typical output impedance.
16	$V_{\scriptscriptstyle DDA}$	Power		Analog supply pin.

NOTE: Pullup refers to internal input resistors. See Table 2, Pin Characteristics, for typical values.

Table 2. Pin Characteristics

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
C <sub>IN</sub>	Input Capacitance			4		pF
C <sub>PD</sub>	Power Dissipation Capacitance	$V_{DD}$ , $V_{DDA}$ , $V_{DDO} = 3.465V$		8		pF
R <sub>PULLUP</sub>	Input Pullup Resistor			51		kΩ
R <sub>OUT</sub>	Output Impedance			20		Ω

TABLE 3A. CONTROL FUNCTION TABLE

Control Inputs	Output
OE	REF_CLK
0	Hi-Z
1	Active

TABLE 3B. M DIVIDER FUNCTION TABLE

Contro	I Inputs	Feedback Divider Ratio
M1	MO	reedback Divider hallo
0	0	÷32
0	1	÷25
1	0	÷24
1	1	÷15 (default)

TABLE 3C. N DIVIDER FUNCTION TABLE

Contro	l Inputs	Output Divider Betie
N1	N0	Output Divider Ratio
0	0	÷3
0	1	÷4
1	0	÷5
1	1	÷6 (default)



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#### ABSOLUTE MAXIMUM RATINGS

Supply Voltage, V<sub>DD</sub> 4.6V

Inputs,  $V_I$  -0.5V to  $V_{DD}$  + 0.5 V

Outputs,  $V_{O}$  -0.5V to  $V_{DD}$  + 0.5V

Package Thermal Impedance, θ<sub>IA</sub> 51.5°C/W (0 Ifpm)

Storage Temperature, T<sub>STG</sub> -65°C to 150°C

NOTE: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the *DC Characteristics* or *AC Characteristics* is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

Table 4A. Power Supply DC Characteristics,  $V_{DD} = V_{DDA} = V_{DDO} = 3.3V \pm 5\%$ ,  $T_A = 0^{\circ}C$  to  $70^{\circ}C$ 

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V <sub>DD</sub>	Core Supply Voltage		3.135	3.3	3.465	V
V <sub>DDA</sub>	Analog Supply Voltage		3.135	3.3	3.465	V
V <sub>DDO</sub>	Output Supply Voltage		3.135	3.3	3.465	V
I <sub>DD</sub>	Power Supply Current			70		mA
I <sub>DDA</sub>	Analog Supply Current			6		mA
I <sub>DDO</sub>	Output Supply Current			27		mA

**Table 4B. LVCMOS/LVTTL DC Characteristics,**  $V_{DD} = V_{DDA} = V_{DDO} = 3.3V \pm 5\%$ , Ta = 0°C to 70°C

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
V <sub>IH</sub>	Input High Voltage			2		V <sub>DD</sub> + 0.3	V
V <sub>IL</sub>	Input Low Voltage			-0.3		0.8	V
I <sub>IH</sub>	Input High Current	OE, M1:0, N1:0	$V_{DD} = V_{IN} = 3.465V$			5	μΑ
I <sub>IL</sub>	Input Low Current	OE, M1:0, N1:0	$V_{DD} = 3.465V, V_{IN} = 0V$	-150			μΑ
V <sub>OH</sub>	Output High Voltage; NOTE 1			2.6			V
V <sub>OL</sub>	Output Low Voltage;	NOTE 1				0.5	V

NOTE 1: Outputs terminated with  $50\Omega$  to  $V_{DD}/2$ . See Parameter Measurement Information Section,

#### TABLE 5. CRYSTAL CHARACTERISTICS

Parameter	Test Conditions	Minimum	Typical	Maximum	Units
Mode of Oscillation		F	undamenta	I	
Frequency		15.3125		42.67	MHz
Equivalent Series Resistance (ESR)				50	Ω
Shunt Capacitance				7	pF
Drive Level				1	mW

<sup>&</sup>quot;3.3V Output Load Test Circuit".



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Table 6. AC Characteristics,  $V_{DD} = V_{DDA} = V_{DDO} = 3.3V \pm 5\%$ , Ta = 0°C to 70°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
4	Output Fraguancy			100		MHz
OUT	f <sub>out</sub> Output Frequency			106.25		MHz
£:;t/(C)	RMS Phase Jitter (Random);	100MHz, Integration Range: 637kHz to 10MHz		0.54		ps
fjit(Ø) NOTE 1	NOTE 1	106.25MHz, Integration Range: 637kHz to 10MHz		0.38		ps
t <sub>R</sub> / t <sub>F</sub>	Output Rise/Fall Time	20% to 80%		470		ps
odc	Output Duty Cycle			50		%

All parameters are characterized @ 100MHz and 106.25MHz.

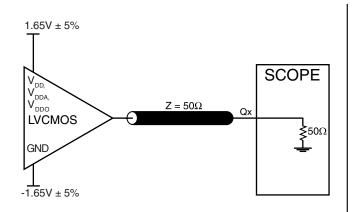
NOTE 1: Please refer to the Phase Noise Plot.

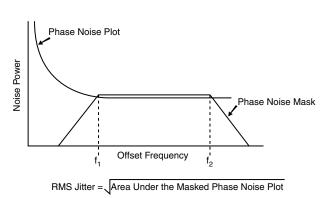


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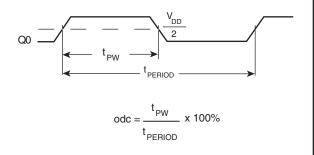
## PARAMETER MEASUREMENT INFORMATION

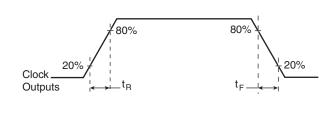




#### 3.3V OUTPUT LOAD AC TEST CIRCUIT

#### RMS PHASE JITTER





#### OUTPUT DUTY CYCLE/PULSE WIDTH/PERIOD

#### **OUTPUT RISE/FALL TIME**

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### **APPLICATION INFORMATION**

#### Power Supply Filtering Techniques

As in any high speed analog circuitry, the power supply pins are vulnerable to random noise. The ICS840001-34 provides separate power supplies to isolate any high switching noise from the outputs to the internal PLL.  $V_{\rm DD},\,V_{\rm DDA}$  and  $V_{\rm DDO}$  should be individually connected to the power supply plane through vias, and bypass capacitors should be used for each pin. To achieve optimum jitter performance, power supply isolation is required. Figure 1 illustrates how a  $10\Omega$  resistor along with a  $10\mu F$  and a  $.01\mu F$  bypass capacitor should be connected to each  $V_{\rm DDA}$  pin.

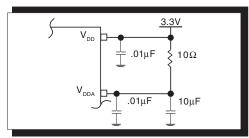
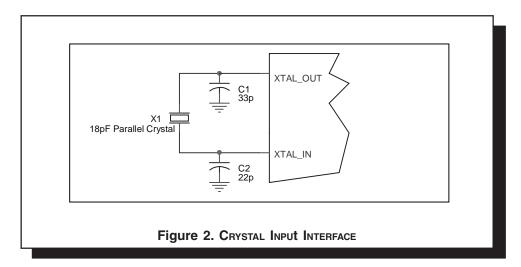


FIGURE 1. POWER SUPPLY FILTERING

#### CRYSTAL INPUT INTERFACE

The ICS840001-34 has been characterized with 18pF parallel resonant crystals. The capacitor values, C1 and C2, shown in *Figure 2* below were determined using a 26.5625MHz, 18pF par-

allel resonant crystal and were chosen to minimize the ppm error. The optimum C1 and C2 values can be slightly adjusted for different board layouts.





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## **RELIABILITY INFORMATION**

Table 7.  $\theta_{\text{JA}} \text{vs. Air Flow Table for 16 Lead VFQFN}$ 

 $\theta_{JA}$  at 0 Air Flow (Linear Feet per Minute)

0

Multi-Layer PCB, JEDEC Standard Test Boards

51.5°C/W

TRANSISTOR COUNT

The transistor count for ICS840001-34 is: 2805



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#### PACKAGE OUTLINE - K SUFFIX FOR 16 LEAD VFQFN

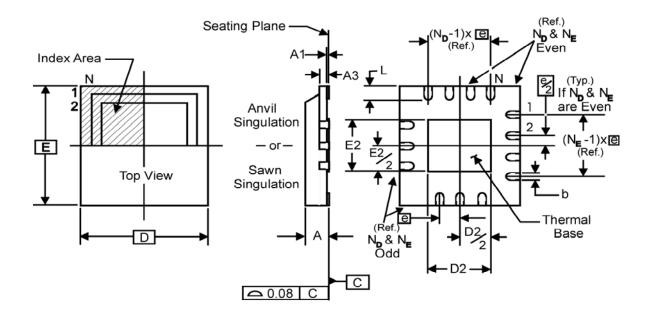


TABLE 8. PACKAGE DIMENSIONS

JEDEC VARIATION ALL DIMENSIONS IN MILLIMETERS						
SYMBOL	MINIMUM	MAXIMUM				
N	1	6				
Α	0.80	1.0				
A1	0	0.05				
А3	0.25 Re	eference				
b	0.18 0.30					
е	0.50 E	BASIC				
N <sub>D</sub>	4	1				
N <sub>E</sub>	4	1				
D	3	.0				
D2	0.25	1.25				
E	3.0					
E2	0.25	1.25				
L	0.30	0.50				

Reference Document: JEDEC Publication 95, MO-220



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#### TABLE 9. ORDERING INFORMATION

Part/Order Number	Marking	Package	Package Shipping Packaging	
ICS840001AK-34	1A34	16 Lead VFQFN	tray	0°C to 70°C
ICS840001AK-34	1A34	16 Lead VFQFN	2500 tape & reel	0°C to 70°C

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